

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

pplication of

Joon-seop Kwak et al.

Filing Date:

Application No.: 10/673,251

September 30, 2003

Group Art Unit: 2812

Examiner: SAVITRI MULPURI

Confirmation No.: 2845

Title: GAN BASED GROUP III-V NITRIDE SEMICONDUCTOR LIGHT-EMITTING DIODE AND METHOD

FOR FABRICATING THE SAME

PETITION FOR EXTENSION OF TIME

Commissioner for Patents P.O. Box 1450 - Alexandria, VA 22313-1450

Sir:

The following extension of time is requested to: respond to Final Office Action dated September 3, 2004

	one month toJan	uary 3, 2005	 \$60.00 (2251)	× \$120.00 (1251)
	☐ The shortened statutory period has been reset by an Advisory Action dated			
X	An extension fee in the amount of \$ 120.00 is enclosed.			
	Charge to Deposit Account No. 02-4800.			
	Charge	to credit card.	Form PTO-2038	is attached.
The Director is hereby authorized to charge any appropriate fees under 37 C.F.R. §§1.16, 1.17 and 1.21 that may be required by this paper, and to credit any overpayment, to Deposit Account No. 02-4800. This paper is submitted in duplicate.				
			Respectfully submitted,	
P.O. Box 1404 Alexandria, Virginia 22313-1404 (703) 836-6620			BURNS, DOANE, SWECKER & MATHIS, AL.P. By Charles F. Wieland III	
Date:	January 3, 2005		Registration	n N6. 33,096

01/04/2005 SSITHIB1 00000069 10673251

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120.00 GP

